

## 2-line ESD Protection Diode in SOT490

#### **Features**

- Small SOT490 package
- · Very low leakage current
- ESD protection to IEC 61000-4-2 ± 30 kV (Air)
- ESD protection to IEC 61000-4-2 ± 20 kV (Contact)
- Two line asymmetrical ESD-protection (BiAs)
- One line asymmetrical ESD-protection (BiSy)
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

### **Mechanical Data**

Case: SOT490 (plastic package) Lead free; non magnetic

**Molding Compound Flammability Rating:** 

UL 94 V-0

**Terminals:** High temperature soldering guaranteed:

260 °C/10 sec. at terminals

Weight: 2.5 mg

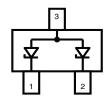
**Packaging Codes/Options:** 

GS18 = 10 k per 13" reel (8 mm tape), 10 k/box GS08 = 3 k per 7" reel (8 mm tape), 15 k/box









### Marking:



4 = date code (Example only) A1 = Type Code for VESD05A2-03F

### **Maximum Ratings and Thermal Characteristics**

 $T_A = 25$  °C unless otherwise specified

Parameter	Symbol	Value	Unit
ESD Air Discharge per IEC 61000-4-2	V <sub>ESD</sub>	± 30	kV
ESD Contact Discharge per IEC 61000-4-2	V <sub>ESD</sub>	± 20	kV
Operating Temperature	T <sub>J</sub>	- 40 to + 125	°C
Storage Temperature	T <sub>STG</sub>	- 55 to + 150	°C

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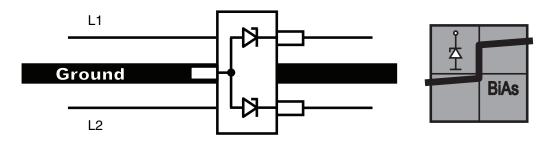


## **Electrical Characteristics**

 $T_A = 25$  °C unless otherwise specified

BiAs-Mode (2-line Bidirectional Asymmetrical protection mode)

With the **VESD05A2-03F** two signal or data lines (L1, L2) can be clamped to ground. Due to the different clamping levels in forward and reverse direction the **VESD05A2-03F** clamping behavior is **Bi**directional and **As**ymmetric (**BiAs**).



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Parameter	Test Conditions	Synbol	Min.	Тур.	Max.	Unit
Reverse Stand-Off Voltage	at max. reverse current	V <sub>RWM</sub>	5			V
Max. Reverse current	at $V_R = 5 V$	I <sub>R</sub>			0.1	μΑ
Max. Clamping voltage	at I <sub>PP</sub> = 3 A Acc. IEC 61000-4-5	V <sub>C</sub>		8.9	11	V
Max. Peak pulse current	Acc. IEC 61000-4-5 See Fig. 1	I <sub>PPM</sub>			3	А
Min. Reverse Breakdown Voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	6.0	6.8	7.5	٧
Capacitance	at $V_R = 0 V$ ; $f = 1 MHz$	C <sub>D</sub>		20	23	pF
Forward voltage	at $I_F = 200 \text{ mA}; t_p < 300 \mu\text{s}$	V <sub>F</sub>		0.95	1.2	V
ESD-Clamping voltage (Overshoot)	at + 8 kV ESD-pulse acc. IEC 61000-4-2	V <sub>C-ESD</sub>		+79		V
ESD-Clamping voltage (Undershoot)	at - 8 kV ESD-pulse acc. IEC 61000-4-2	V <sub>C-ESD</sub>		-72		V

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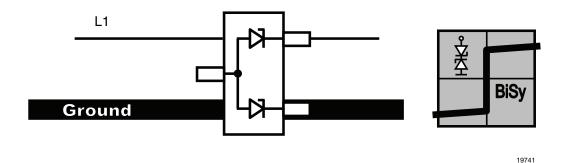


**BiSy**-Mode (1-line **Bi**directional **Sy**mmetrical protection mode)

Single-Line Bidirectional Symmetrical ESD-Protection (BiSy)

With the VESD05A2-03F one signal or data line (L1) can be clamped to ground. Due to the same clamping levels in postive and negative direction the VESD05A2-03F voltage clamping behaviour is Bidirectional and Symmetrical (BiSy).

In the BiSy-mode Pin no. 3 must not be connected. The load capacitance is about the half of the capacitance of the BiAs-mode.



Parameter	Test Conditions	Synbol	Min.	Тур.	Max.	Unit
Reverse Stand-Off Voltage	at max. reverse current	$V_{RWM}$	5.5			V
Max. Reverse current	at V <sub>R</sub> = 5.5 V	I <sub>R</sub>			0.1	μΑ
Max. Clamping voltage	at I <sub>PP</sub> = 3 A Acc. IEC 61000-4-5	V <sub>C</sub>		10.6	12	V
Max. Peak pulse current	Acc. IEC 61000-4-5 See Fig. 1	I <sub>PPM</sub>			3	Α
Min. Reverse Breakdown Voltage	at I <sub>R</sub> = 1 mA	V <sub>BR</sub>	6.7	7.5	8.2	V
Capacitance	at $V_R = 0 V$ ; $f = 1 MHz$	C <sub>D</sub>		10	12	pF
ESD-Clamping voltage	at ± 8 kV ESD-pulse	$V_{C-ESD}$		± 100		V

acc. IEC 61000-4-2

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### **Typical Characteristics**

 $T_A = 25$  °C unless otherwise specified

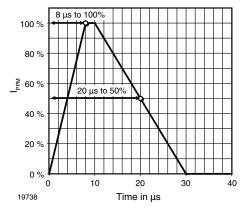


Figure 1. 8/20  $\mu$ s Peak Pulse Current wave form acc. IEC 61000-4-5

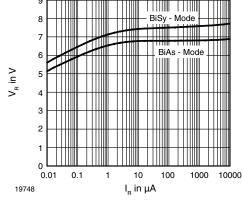


Figure 4. Typical Reverse Voltage  $V_R$  vs. Reverse Current  $I_R$ 

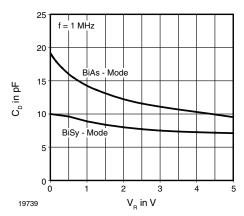


Figure 2. Typical Capacitance  $C_D$  vs. Reverse Voltage  $V_R$ 

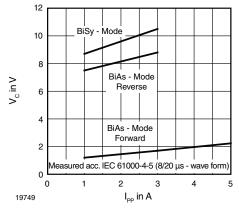


Figure 5. Typical Clamping Voltage vs. Peak Pulse Current I<sub>PP</sub>

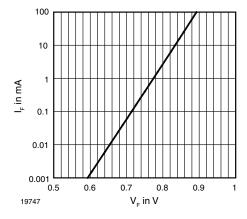


Figure 3. Typical Forward Current  $I_F$  vs. Forward Voltage  $V_F$ 

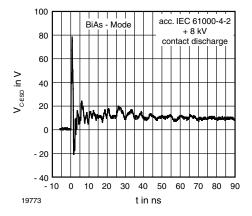


Figure 6. Typical Clamping performance at 8 kV contact discharge (Acc. IEC 61000-4-2)



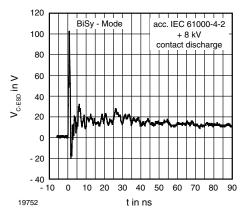


Figure 7. Typical Clamping performance at 8 kV contact discharge (Acc. IEC 61000-4-2)

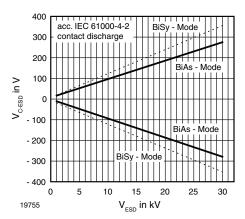


Figure 10. Typical clamping voltage at ± ESD contact discharge (Acc. IEC 61000-4-2)

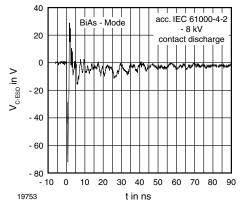


Figure 8. Typical Clamping performance at - 8 kV contact discharge (Acc. IEC 61000-4-2)

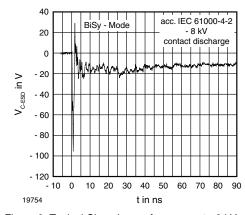
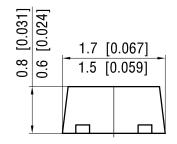
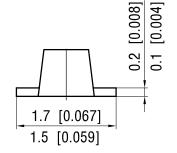


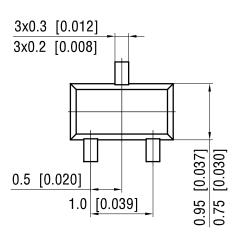
Figure 9. Typical Clamping performance at - 8 kV contact discharge (Acc. IEC 61000-4-2)



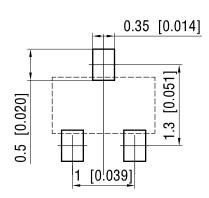
# Package Dimensions in mm (Inches) - SOT490







foot print recommendation:



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### **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

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